Solutions to  $\it The \ Art \ of \ Electronics \ 3rd \ Edition$ 

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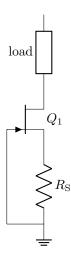
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# Solutions for Chapter 3

### Exercise 3.1

Figure 1.1: JFET current source



From Figure 3.21 of the book, one can see that a drain current equal to  $1\,\mathrm{mA}$  corresponds to a gate-source voltage of  $-0.6\,\mathrm{V}$ . Therefore:

$$R_{\rm S} = \frac{0.6\,\mathrm{V}}{1\,\mathrm{mA}} = 600\,\Omega$$

#### Exercise 3.2

At  $V_{\text{GS}} = V_{\text{G0}}$ :

$$r_{\mathrm{GS}} = r_{\mathrm{G0}} = \frac{1}{2k \left( V_{\mathrm{G0}} - V_{\mathrm{th}} \right)}$$

The ratio between  $r_{\rm DS}$  and  $R_{\rm G0}$  returns:

$$\frac{r_{\rm DS}}{r_{\rm G0}} = \frac{2k \left(V_{\rm G0} - V_{\rm th}\right)}{2k \left(V_{\rm GS} - V_{\rm th}\right)}$$

### Exercise 3.3

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Being  $g_{\rm m}$  the differential conductance of the FET operated in aturation region, it can be expressed as:

$$g_{\rm m} = \frac{\partial I_{\rm D}}{\partial V_{\rm GS}} = \frac{\partial}{\partial V_{\rm GS}} k \left( V_{\rm GS} - V_{\rm th} \right)^2 = 2k \left( V_{\rm GS} - V_{\rm th} \right)$$

Therefore:

$$g_{\rm m} = \frac{1}{r_{\rm DS}}$$

#### Exercise 3.4

(a) The voltage across the drain-gate capacitance when the JFET is switched on  $(V_{DS} = 0 \text{ V})$  is equal to 50 V-10 V=40 V. Considering a maximum current across this capacitance equal to 1 mA:

$$t_{
m ON} = rac{40\,{
m V}\,200\,{
m pF}}{1\,{
m mA}} = 8\,{
m \mu s}$$

(b) Since the current is equal to the charge over time, we have:

$$t_{\rm ON} = \frac{40\,\mathrm{nC}}{1\,\mathrm{mA}} = 40\,\mathrm{\mu s}$$

Exercise 3.5 TODO: write solution

Exercise 3.6 TODO: write solution

Exercise 3.7 TODO: write solution

Exercise 3.8 TODO: write solution

Exercise 3.9 TODO: write solution

Exercise 3.10 TODO: write solution

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